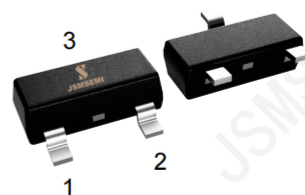
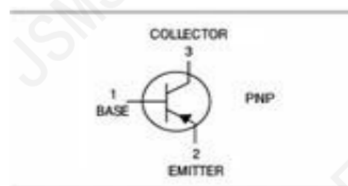


Features

- Epitaxial planar die construction
- Complimentary to BC817
- High collector current
- High current gain
- Low collector-emitter saturation voltage



SOT-23



Mechanical Data

- Case: SOT-23
- Terminals: Tin-plated; solderability per MIL-STD-202, Method 208

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
BC807-16-JSM	SOT-23	3000 pcs / Tape & Reel	5A

Maximum Ratings (@ T_A = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Collector-Base Breakdown Voltage	V _{CBO}	-50	V
Collector-Emitter Breakdown Voltage	V _{CEO}	-45	V
Emitter-Base Breakdown Voltage	V _{EBO}	-5	V
Continuous Collector Current	I _C	-0.5	A

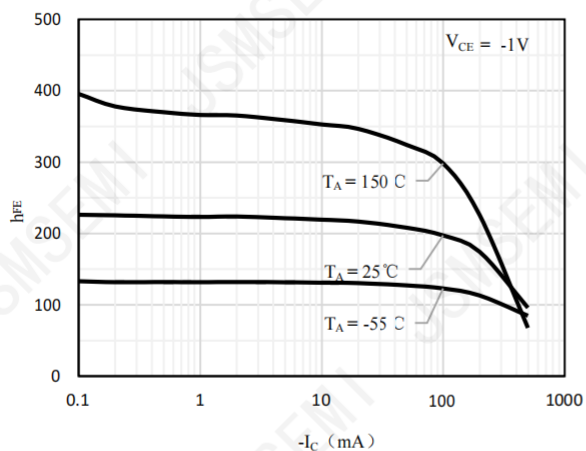
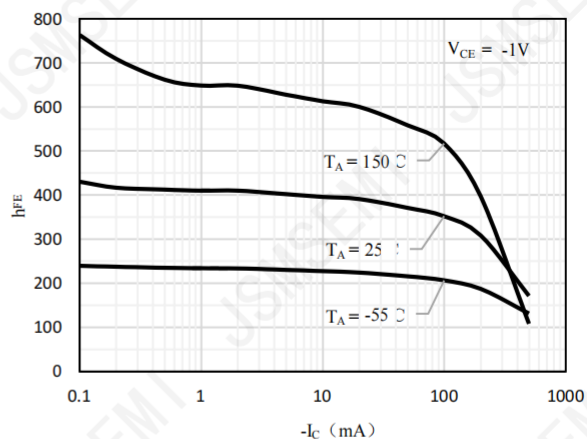
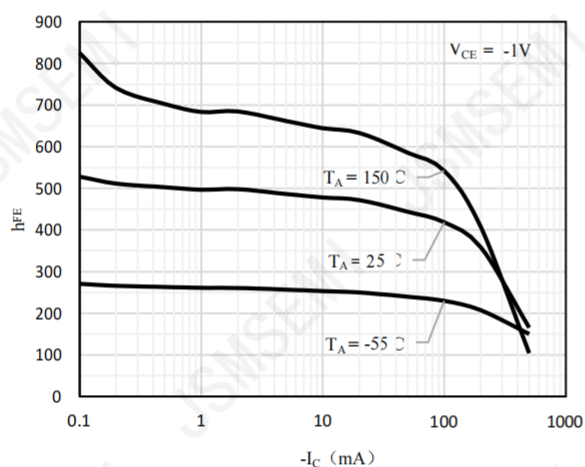
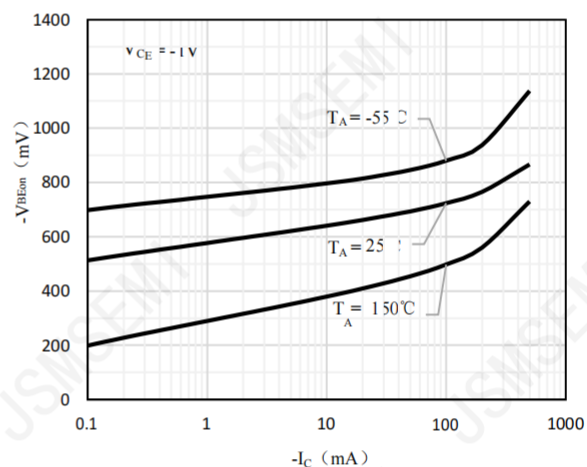
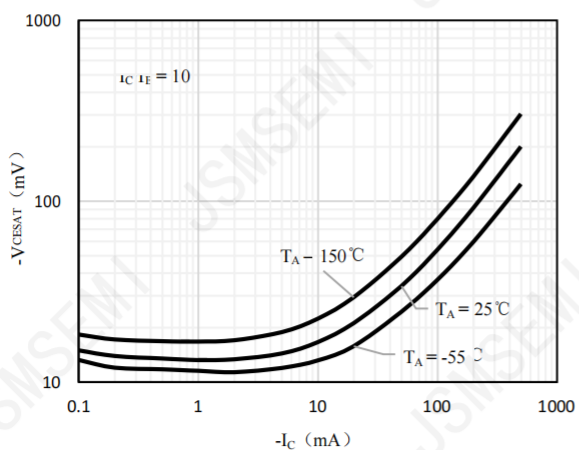
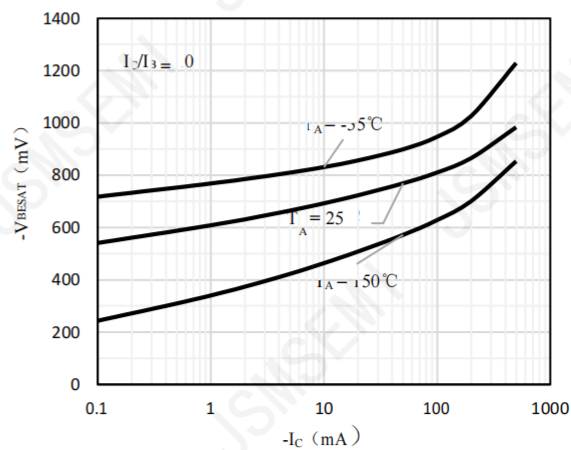
Thermal Characteristics

Parameter	Symbol	Value	Unit
Power Dissipation	P _D	300	mW
Thermal Resistance Junction-to-Air *1	R _{θJA}	395	°C/W
Thermal Resistance Junction-to-Case *1	R _{θJC}	218	°C/W
Thermal Resistance Junction-to-Lead *1	R _{θJL}	191	°C/W
Operating junction Temperature	T _J	-55 ~ +150	°C
Storage Temperature Range	T _{STG}	-55 ~ +150	°C

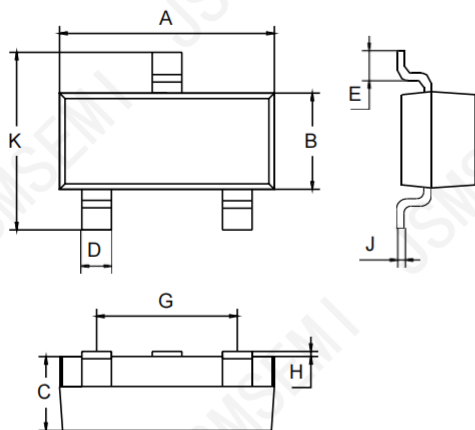
Note 1: The data tested by surface mounted on a 15mm * 15mm * 1mm FR4-epoxy P.C.B

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -10\mu\text{A}, I_E = 0$	-50	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -10\text{mA}, I_B = 0$	-45	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -10\mu\text{A}, I_C = 0$	-5	-	-	V
Collector Cut-off Current	I_{CBO}	$V_{CB} = -25\text{V}, I_E = 0$	-	-	-100	nA
Emitter Cut-off Current	I_{EBO}	$V_{EB} = -4\text{V}, I_C = 0$	-	-	-100	nA
DC Current Gain	h_{FE}	$V_{CE} = -1\text{V}, I_C = -100\text{mA}$	100	197	250	-
		$V_{CE} = -1\text{V}, I_C = -300\text{mA}$	60	-	-	-
Collector-emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -500\text{mA}, I_B = -50\text{mA}$	-	-	-0.7	V
Base-emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = -500\text{mA}, I_B = -50\text{mA}$	-	-	-1.2	V
Transition Frequency	f_T	$I_C = -10\text{mA}, V_{CE} = -5\text{V}$	-	200	-	MHz
Collector Output Capacitance	C_{OBO}	$V_{CB} = -10\text{V}, I_E = 0, f = 1\text{MHz}$	-	-	10	pF

Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Fig 1 h_{FE} vs. I_C (BC807-16)

Fig 2 h_{FE} vs. I_C (BC807-25)

Fig 3 h_{FE} vs. I_C (BC807-40)

Fig 4 $V_{BE(ON)}$ vs. I_C

Fig 5 $V_{CE(sat)}$ vs. I_C

Fig 6 $V_{BE(sat)}$ vs. I_C

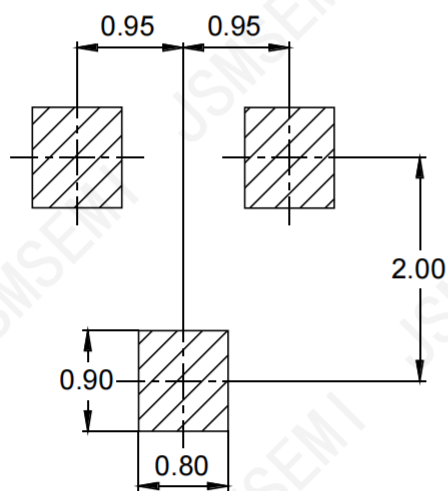
Package Outline Dimensions (Unit: mm)



SOT-23		
Dimension	Min.	Max.
A	2.70	3.10
B	1.10	1.50
C	0.9	1.1
D	0.3	0.5
E	0.35	0.48
G	1.80	2.00
H	0.02	0.1
J	0.05	0.15
K	2.20	2.60

Package Outline Dimensions (Unit: mm)

SOT-23



Revision History

Rev.	Change	Date
V1.0	Initial version	2/23/2024

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